#### DISCRETE SEMICONDUCTORS

## DATA SHEET

# BYW29EX series Rectifier diodes ultrafast, rugged

**Product specification** 

October 1998



NXP Semiconductors Product specification

## Rectifier diodes ultrafast, rugged

#### **BYW29EX series**

#### **GENERAL DESCRIPTION**

#### **QUICK REFERENCE DATA**

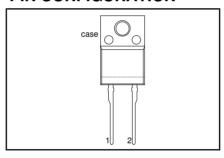
Glass passivated epitaxial rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, ultra-fast recovery times, soft recovery characteristic and guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
	BYW29EX-	150	200	
V <sub>RRM</sub>	Repetitive peak reverse voltage	150	200	V
V <sub>F</sub> I <sub>F(AV)</sub> t <sub>rr</sub> I <sub>RRM</sub>	Forward voltage Forward current Reverse recovery time Repetitive peak reverse current	0.895 8 25 0.2	0.895 8 25 0.2	V A ns A

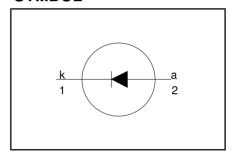
#### **PINNING - SOD113**

PIN	DESCRIPTION			
1	cathode			
2	anode			
case	isolated			

#### **PIN CONFIGURATION**



#### **SYMBOL**



#### **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	AX.	UNIT
V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage		1 1 1	<b>-150</b> 150 150 150	<b>-200</b> 200 200 200	<<<
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; $\delta = 0.5$ ; $T_{hs} \le 106 ^{\circ}\text{C}$ sinusoidal; $a = 1.57$ ;	-		8	A
1	RMS forward current	T <sub>hs</sub> ≤ 109 °C	_		.3 I.3	A A
I <sub>F(RMS)</sub> I <sub>FRM</sub>	Repetitive peak forward current	$t = 25 \mu s; δ = 0.5;$ $T_{hs} \le 106 °C$	-		6	Ä
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-		80 88	A A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>RWM(max)</sub> t = 10 ms	-		2	A <sup>2</sup> s
I <sub>RRM</sub>	Repetitive peak reverse current Non-repetitive peak reverse	$t_p = 2 \mu s; \delta = 0.001$ $t_p = 100 \mu s$	-		.2 .2	A A
I <sub>RSM</sub>	current	ι <sub>p</sub> = 100 μS	-	"	.∠	
T <sub>stg</sub>	Storage temperature Operating junction temperature		-40 -		50 50	C

<sup>1</sup> Neglecting switching and reverse current losses

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#### **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>C</sub>	ı	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

#### **ISOLATION LIMITING VALUE & CHARACTERISTIC**

T<sub>hs</sub> = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	-		2500	V
C <sub>isol</sub>	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-hs}$ $R_{th j-a}$	heatsink	with heatsink compound without heatsink compound in free air		- - 55	5.5 7.2 -	K/W K/W K/W

#### **STATIC CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	$I_F = 8 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.80	0.895	V
		$I_F = 8 \text{ A}$	-	0.92	1.05	V
		$I_{\rm F} = 20 \text{ A}$	-	1.1	1.3	V
l <sub>R</sub>	Reverse current	$\dot{V}_R = V_{RWM}; T_i = 100 ^{\circ}C$	-	0.2	0.6	mA
		$V_{R} = V_{RWM}$	-	2	10	μΑ

#### **DYNAMIC CHARACTERISTICS**

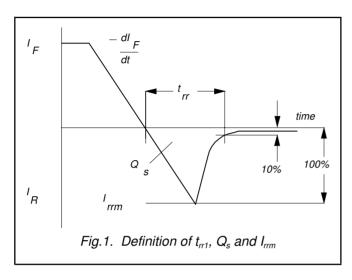
T<sub>i</sub> = 25 °C unless otherwise stated

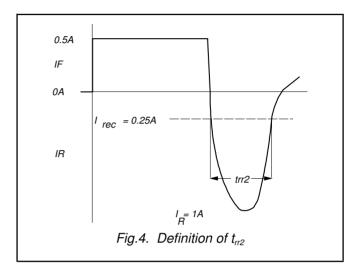
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q <sub>s</sub>	Reverse recovery charge	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A}/\mu\text{s}$	-	4	11	nC
t <sub>rr1</sub>	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ - $dI_F/dt = 100 \text{ A/}\mu\text{s}$	-	20	25	ns
$V_{\rm fr}$	Reverse recovery time Forward recovery voltage	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A; } I_{rec} = 0.25 \text{ A}$ $I_E = 1 \text{ A; } dI_E/dt = 10 \text{ A/}\mu\text{s}$	-	15 1	20 -	ns V

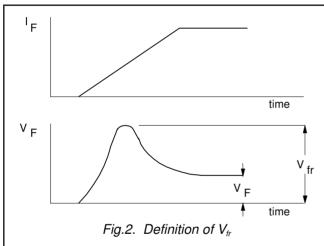
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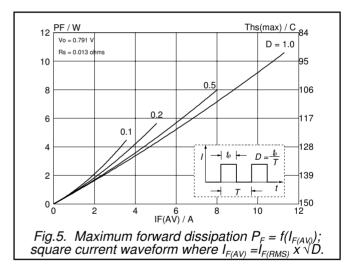
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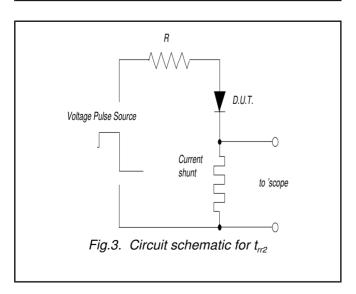
#### BYW29EX series











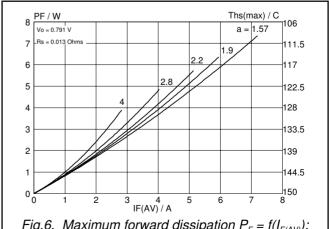
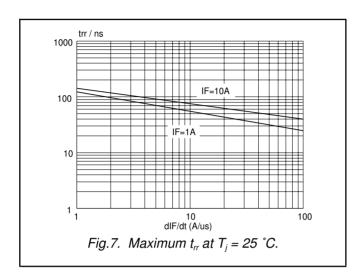
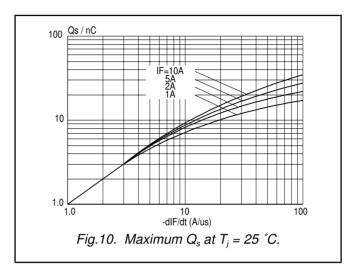


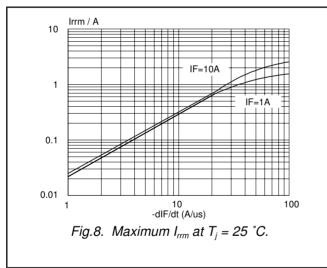
Fig.6. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = form factor  $= I_{F(RMS)} / I_{F(AV)}$ .

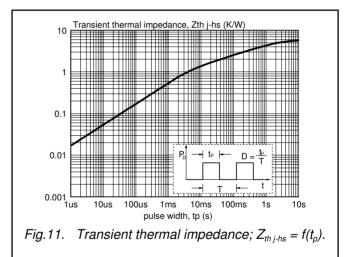
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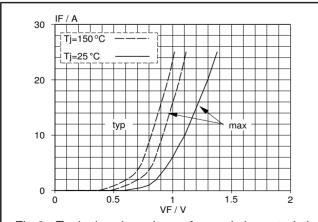
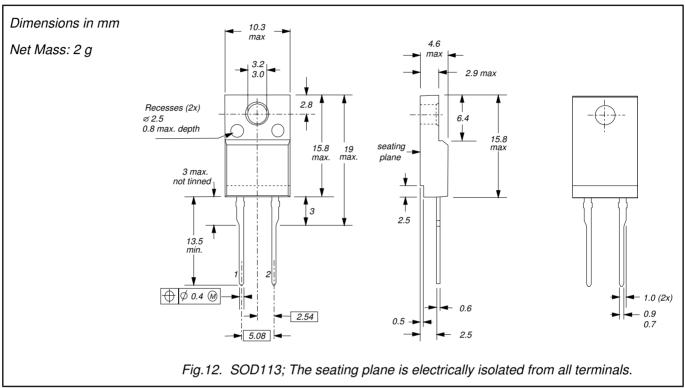


Fig.9. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

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#### **MECHANICAL DATA**



#### **Notes**

- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

#### Legal information

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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